HEF4952B

Dual 3-channel analog multiplexer/demultiplexer with supplementary switches

Rev. 03 — 16 December 2009 Product data sheet

1. General description

The HEF4952B is a dual 3-channel analog multiplexer/demultiplexer with supplementary switches and common select logic. Each switch features three independent inputs/outputs (pins nY0, nY1 and nY2) an input/output nY3 that can be connected to nY2 or V_{SS} and an input/output (nZ) common to nY0, nY1 and nY2. Three digital select inputs (S1, S2 and S3) are common to both switches. Inputs include clamp diodes, this enables the use of current limiting resistors to interface inputs in excess of V_{DD}.

V_{SS} and V_{DD} are the digital control supply pins.

The HEF4952B is suitable for use over the full industrial (−40 °C to +85 °C) temperature range.

2. Features

- Fully static operation
- 5 V, 10 V, and 15 V parametric ratings
- Schmitt-trigger action at control inputs
- Small signal switch
- Standardized symmetrical output characteristics
- Operates across the full industrial temperature range −40 °C to +85 °C
- Complies with JEDEC standard JESD 13-B

3. Applications

- Industrial
- Analog multiplexing and demultiplexing
- Digital multiplexing and demultiplexing
- Signal gating

4. Ordering information

Table 1. Ordering information

All types operate from −40 °C to +85 °C.

Type number	Package		
	Name	Description	Version
HEF4952BT	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1

5. Functional diagram

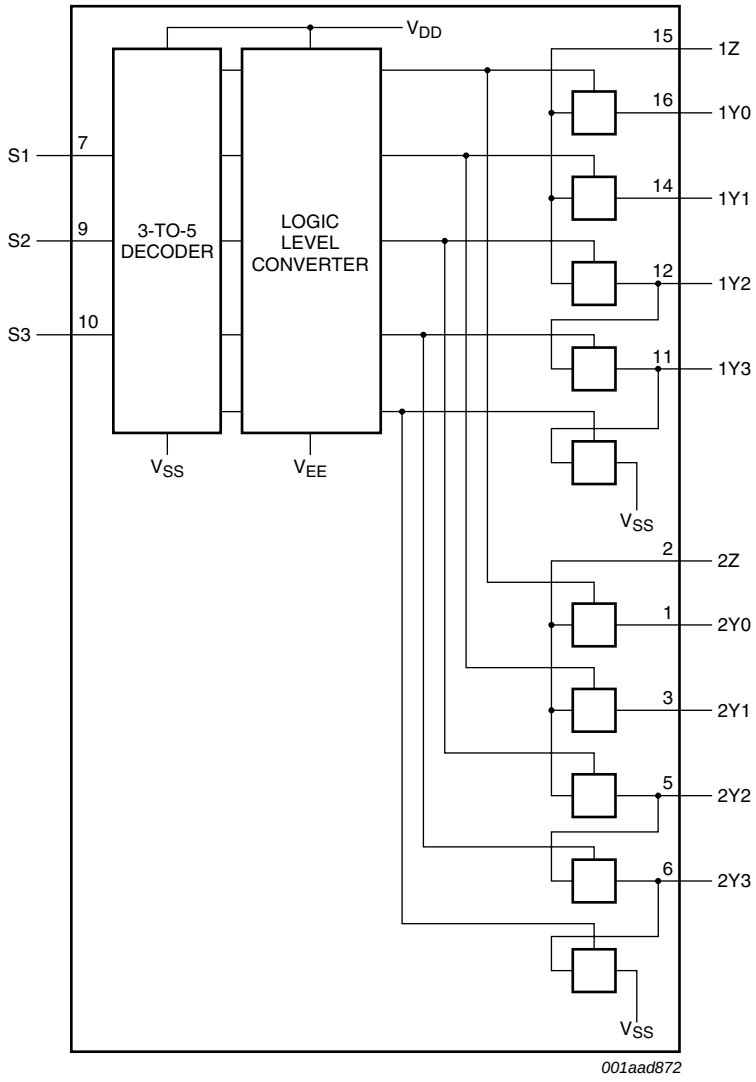


Fig 1. Functional diagram

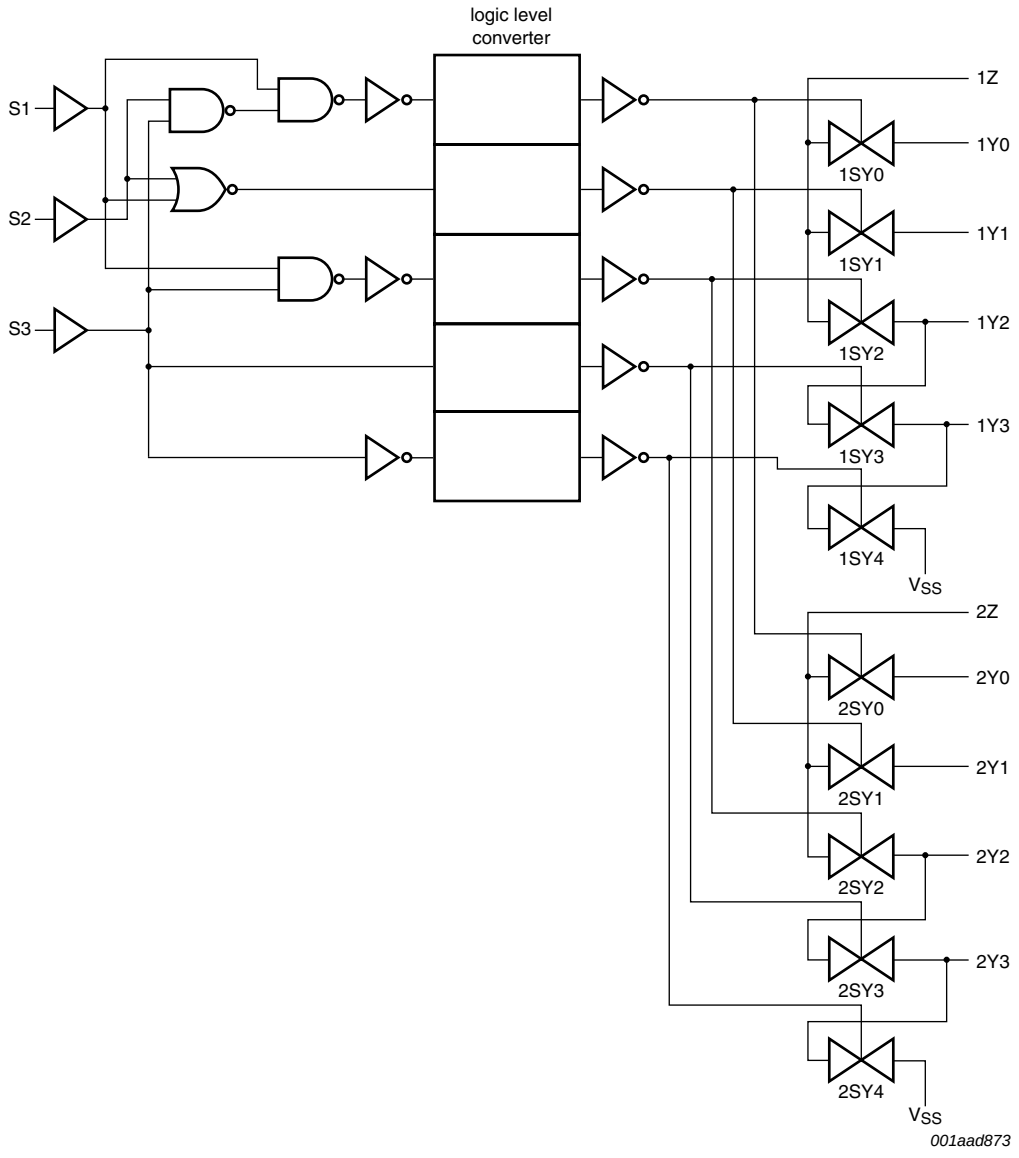


Fig 2. Logic diagram

6. Pinning information

6.1 Pinning

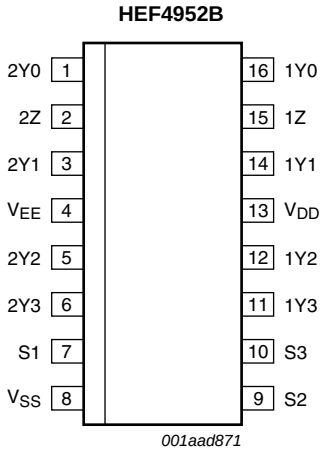


Fig 3. Pin configuration

6.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
V_{EE}	4	supply voltage
V_{SS}	8	ground supply voltage
S1, S2, S3	7, 9, 10	select input
1Y0, 1Y1, 1Y2, 1Y3, 2Y0, 2Y1, 2Y2, 2Y3	16, 14, 12, 11, 1, 3, 5, 6	independent input or output
1Z, 2Z	15, 2	common output or input
V_{DD}	13	supply voltage

7. Functional description

7.1 Function table

Table 3. Function table

Input			Switch				
S3	**S2**	**S1**	**nSY0**	**nSY1**	**nSY2**	**nSY3**	**nSY4**
L	L	L	open	nY1 to nZ	open	open	nY3 to V_{SS}
L	L	H	nY0 to nZ	open	open	open	nY3 to V_{SS}
L	H	L	open	open	nY2 to nZ	open	nY3 to V_{SS}
L	H	H	nY0 to nZ	open	nY2 to nZ	open	nY3 to V_{SS}
H	L	L	open	nY1 to nZ	open	nY2 to nY3	open
H	L	H	nY0 to nZ	open	open	nY2 to nY3	open
H	H	L	open	open	nY2 to nZ	nY2 to nY3	open
H	H	H	open	open	open	nY2 to nY3	open

[1] H = HIGH voltage level;
L = LOW voltage level.

8. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to V_{SS} = 0 V (ground).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{DD}	supply voltage			−0.5	+18	V
V_{EE}	supply voltage	referenced to V_{DD}	[1]	−18	+0.5	V
I_{IK}	input clamping current	pins Sn; $V_I < -0.5$ V or $V_I > V_{DD} + 0.5$ V		-	±10	mA
V_I	input voltage			−0.5	V_{DD} + 0.5	V
$I_{I/O}$	input/output current			-	±10	mA
I_{DD}	supply current			-	50	mA
T_{stg}	storage temperature			−65	+150	°C
T_{amb}	ambient temperature			−40	+85	°C
P_{tot}	total power dissipation	T_{amb} = −40 °C to +85 °C	[2]	-	500	mW
P	power dissipation	per output		-	100	mW

[1] To avoid drawing V_{DD} current out of terminal Z, when switch current flows into terminals Y, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal Z, no V_{DD} current will flow out of terminals Y, and in this case there is no limit for the voltage drop across the switch, but the voltages at Y and Z may not exceed V_{DD} or V_{EE}.

[2] For SO16 package: P_{tot} derates linearly with 8 mW/K above 70 °C.

9. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{DD}	supply voltage	see Figure 4	5	-	15	V
V_{EE}	supply voltage	see Figure 4	-15	-	0	V
V_I	input voltage		0	-	V_{DD}	V
T_{amb}	ambient temperature	in free air	−40	-	+85	°C

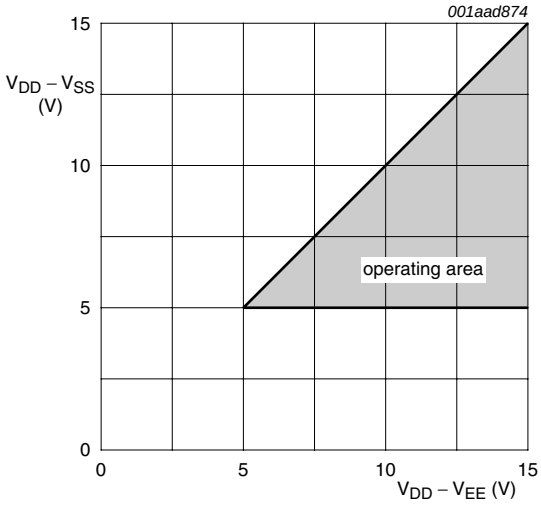


Fig 4. Operating area as a function of the supply voltages

10. Static characteristics

Table 6. Static characteristics

V_{SS} = V_{EE} = 0 V; V_I = V_{SS} or V_{DD} unless otherwise specified.

Symbol	Parameter	Conditions	V_{DD}	T_{amb} = −40 °C		T_{amb} = 25 °C		T_{amb} = 85 °C		Unit
				Min	Max	Min	Max	Min	Max	
I_I	input leakage current		15 V	-	±0.3	-	±0.3	-	±1.0	µA
$I_{S(OFF)}$	OFF-state leakage current	Y port; per channel; see Figure 5	15 V	-	-	-	200	-	-	nA
I_{DD}	supply current	I_O = 0 A	5 V	-	20	-	20	-	150	µA
			10 V	-	40	-	40	-	300	µA
			15 V	-	80	-	80	-	600	µA
C_I	input capacitance	Sn inputs	-	-	-	-	7.5	-	-	pF

10.1 Test circuits

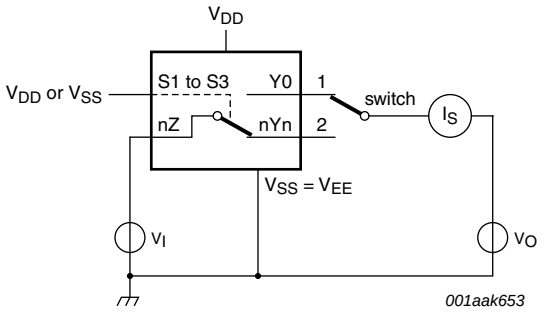


Fig 5. Test circuit for measuring OFF-state leakage current nYn port

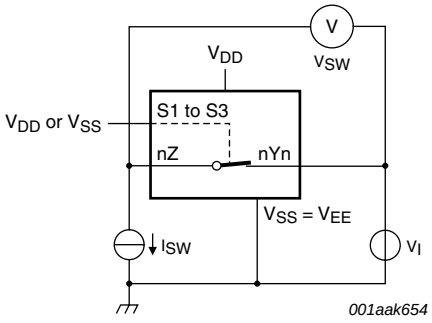
10.2 On resistance

Table 7. ON resistance

T_{amb} = 25 °C; I_{SW} = 200 μA; V_{SS} = V_{EE} = 0 V.

Symbol	Parameter	Conditions	$V_{DD} - V_{EE}$	Typ	Max	Unit
R_{ON}	ON resistance	V_I = 0 V; see Figure 6 and Figure 7	10 V	45	150	Ω
		V_I = 2.5 V; see Figure 6 and Figure 7	10 V	65	365	Ω
		V_I = 5.0 V; see Figure 6 and Figure 7	10 V	110	360	Ω
ΔR_{ON}	ON resistance mismatch between channels	V_I = 2.5 V; see Figure 6	10 V	10	-	Ω

10.2.1 On resistance waveform and test circuit



$R_{ON} = V_{SW} / I_{SW}$.

Fig 6. Test circuit for measuring R_{ON}

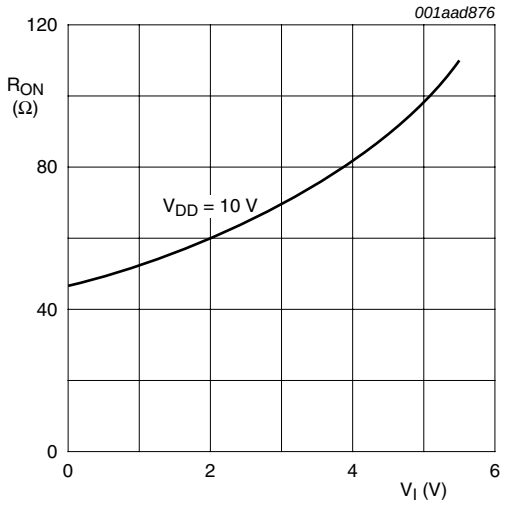


Fig 7. Typical R_{ON} as a function of input voltage

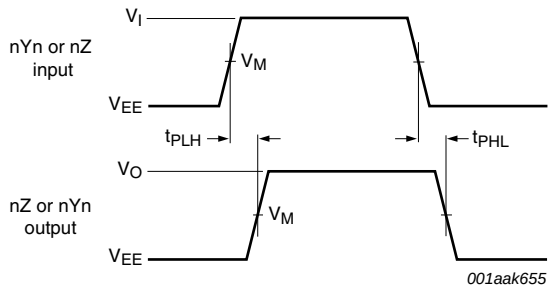
11. Dynamic characteristics

Table 8. Dynamic characteristics

T_{amb} = 25 °C; V_{SS} = V_{EE} = 0 V; for test circuit see Figure 10.

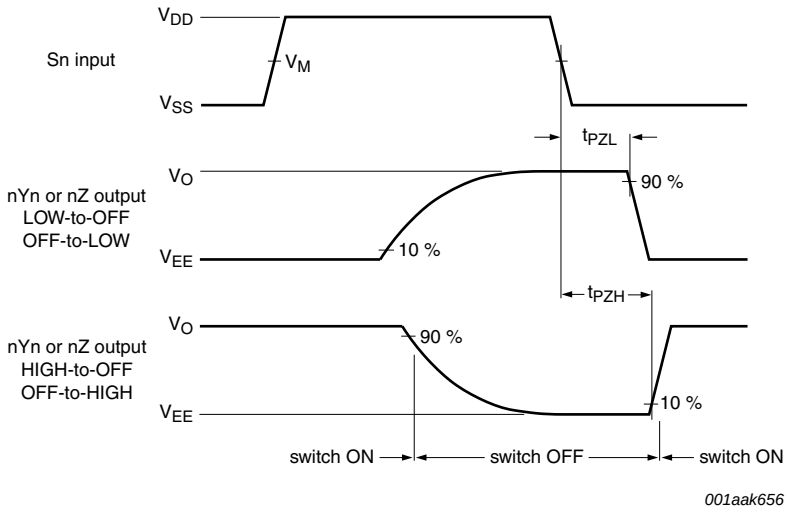
Symbol	Parameter	Conditions	V_{DD}	Typ	Max	Unit
t_{PHL}	HIGH to LOW propagation delay	nYn, nZ to nZ, nYn; V_I = 1.0 V; see Figure 8	5 V	5	-	ns
			10 V	3	6	ns
			15 V	2	-	ns
t_{PLH}	LOW to HIGH propagation delay	nYn, nZ to nZ, nYn; V_I = 1.0 V; see Figure 8	5 V	5	-	ns
			10 V	3	6	ns
			15 V	2	-	ns
t_{PZL}	OFF-state to LOW propagation delay	Sn to nYn, nZ; V_I = V_{EE}; see Figure 9	5 V	125	-	ns
			10 V	50	100	ns
			15 V	35	-	ns
t_{PZH}	OFF-state to HIGH propagation delay	Sn to nYn, nZ; V_I = 1.0 V; see Figure 9	5 V	125	-	ns
			10 V	50	100	ns
			15 V	35	-	ns

11.1 Waveforms and test circuit



Measurement points are given in Table 9.

Fig 8. nYn, nZ to nZ, nYn propagation delays

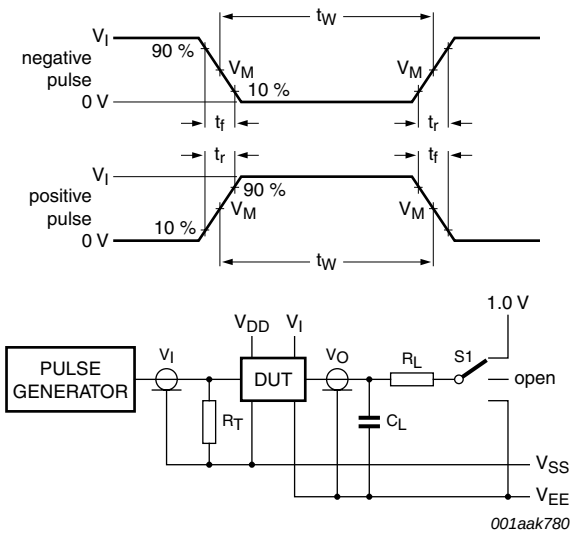


Measurement points are given in Table 9.

Fig 9. Enable and disable times

Table 9. Measurement points

Supply voltage	Input	Output
V_{DD}	V_M	V_M
5 V to 15 V	$0.5V_{DD}$	$0.5V_{DD}$



Test data is given in Table 10.

Definitions:

DUT = Device Under Test.

R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator.

C_L = Load capacitance including test jig and probe.

R_L = Load resistance.

Fig 10. Test circuit for measuring switching times

Table 10. Test data

Input				Load		S1 position			
nYn, nZ	Sn	t_r, t_f	V_M	C_L	R_L	t_{PHL}, t_{PLH}	t_{PZH}	t_{PZL}	Other
V_I or V_{EE}	V_{DD} or V_{SS}	≤ 20 ns	$0.5V_{DD}$	50 pF	10 kΩ	V_{EE}	V_{EE}	1.0 V	V_{EE}

Table 11. Dynamic power dissipation P_D

P_D can be calculated from the formulas shown; $V_{EE} = V_{SS} = 0$ V; $t_r = t_f \leq 20$ ns; $T_{amb} = 25$ °C.

Symbol	Parameter	V_{DD}	Typical formula for P_D (μW)	Where:
P_D	dynamic power dissipation	5 V	$P_D = 1300 \times f_i + \Sigma(f_o \times C_L) \times V_{DD}^2$	f_i = input frequency in MHz;
		10 V	$P_D = 6100 \times f_i + \Sigma(f_o \times C_L) \times V_{DD}^2$	f_o = output frequency in MHz;
		15 V	$P_D = 15600 \times f_i + \Sigma(f_o \times C_L) \times V_{DD}^2$	C_L = output load capacitance in pF;
				V_{DD} = supply voltage in V;
				$\Sigma(f_o \times C_L)$ = sum of the outputs.

11.2 Transfer characteristics

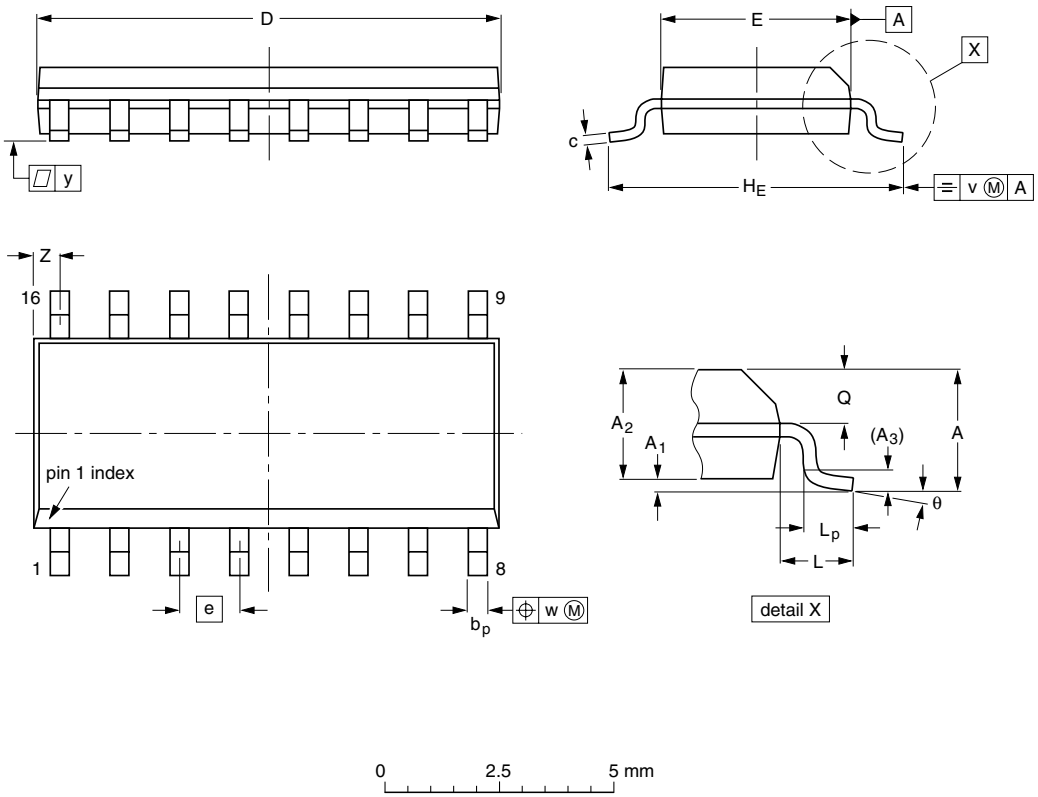
Table 12. Control input characteristics

V_{SS} = V_{EE} = 0 V unless otherwise specified.

Symbol	Parameter	Conditions	T_{amb} = 25 °C		T_{amb} = −40 °C to +85 °C		Unit
			Min	Max	Min	Max	
V_{T+}	positive-going threshold voltage	V_{DD} = 5 V	-	2.90	-	3.00	V
		V_{DD} = 10 V	-	4.37	-	4.50	V
V_{T-}	negative-going threshold voltage	V_{DD} = 5 V	1.03	-	1.00	-	V
		V_{DD} = 10 V	2.10	-	2.00	-	V
V_H	hysteresis voltage	V_{DD} = 5 V	0.16	-	0.10	-	V
		V_{DD} = 10 V	0.11	-	0.10	-	V

12. Package outline

SO16: plastic small outline package; 16 leads; body width 3.9 mm **SOT109-1**



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A_1	A_2	A_3	b_p	c	$D^{(1)}$	$E^{(1)}$	e	H_E	L	L_p	Q	v	w	y	$Z^{(1)}$	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	10.0 9.8	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8° 0°
inches	0.069	0.010 0.004	0.057 0.049	0.01	0.019 0.014	0.0100 0.0075	0.39 0.38	0.16 0.15	0.05	0.244 0.228	0.041	0.039 0.016	0.028 0.020	0.01	0.01	0.004	0.028 0.012	

Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT109-1	076E07	MS-012				~~99-12-27~~ 03-02-19

Fig 11. Package outline SOT109-1 (SO16)

13. Revision history

Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
HEF4952B_3	20091216	Product data sheet	-	HEF4952B_2
Modifications:	• Title changed from 8-channel analog multiplexer/demultiplexer. • Section 1 “General description” modified. • Section 8 “Limiting values” I_{IK} conditions updated. • Abbreviations section removed.			
HEF4952B_2	20091002	Product data sheet	-	HEF4952B_1
HEF4952B_1	20060320	Product data sheet	-	-

14. Legal information

14.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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